

1. General description

Ultrafast power diode in a TO220F-2L plastic package.

2. Features and benefits

- Fast switching
- Isolated plastic package
- Low leakage current
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET or IGBT

3. Applications

- Active PFC in air conditioner
- High frequency switched-mode power supplies
- Power Factor Correction (PFC)

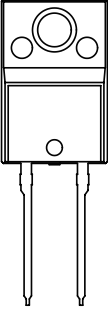
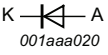
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V _{RRM}	repetitive peak reverse voltage			650			V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3		20			A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; square-wave pulse		40			A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; Fig. 4		180			A
		t _p = 8.3 ms; T _{j(init)} = 25 °C; sine-wave pulse		198			A
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 20 A; T _J = 25 °C; Fig. 6		-	1.90	2.60	V
		I _F = 20 A; T _J = 150 °C; Fig. 6		-	1.50	2.20	V
Dynamic characteristics							
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _J = 25 °C; Fig. 7		-	26	-	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	n.c.	mounting base; isolated		

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYV21MX-650P	TO220F-2L	BYV21MX-650PQ	Tube	50	TO220Fd-2L	02-Aug-2022

7. Marking

Table 4. Marking codes

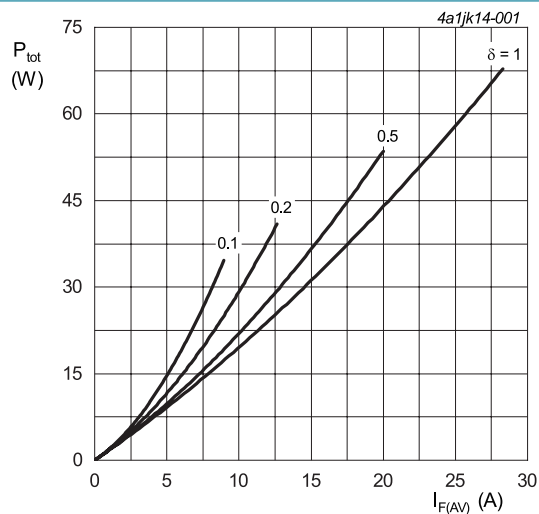
Type number	Marking codes
BYV21MX-650P	BYV21MX 650P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

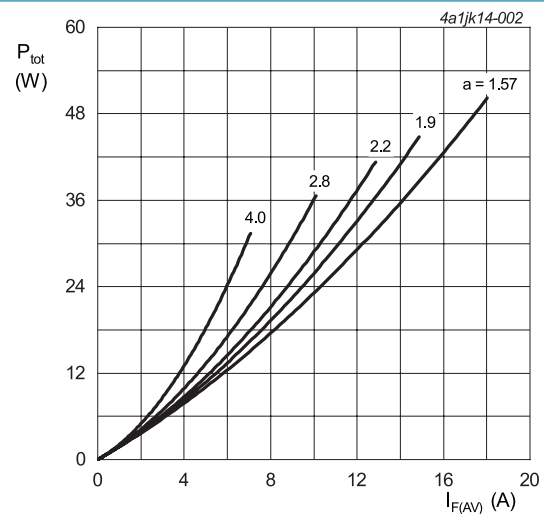
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3		20	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25 \mu s$; square-wave pulse		40	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10 ms$; $T_{j(init)} = 25^\circ C$; sine-wave pulse; Fig. 4		180	A
		$t_p = 8.3 ms$; $T_{j(init)} = 25^\circ C$; sine-wave pulse		198	A
T_{stg}	storage temperature			-65 to 175	$^\circ C$
T_j	junction temperature			-65 to 175	$^\circ C$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 1.714 \text{ V}; R_s = 0.0241 \Omega$$

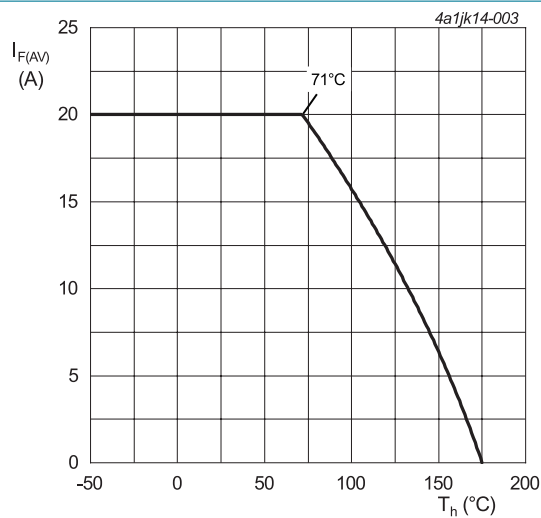
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

$$V_o = 1.714 \text{ V}; R_s = 0.0241 \Omega$$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



square waveform; $\delta = 1$
Fig. 3. Forward current as a function of heatsink temperature; typical values

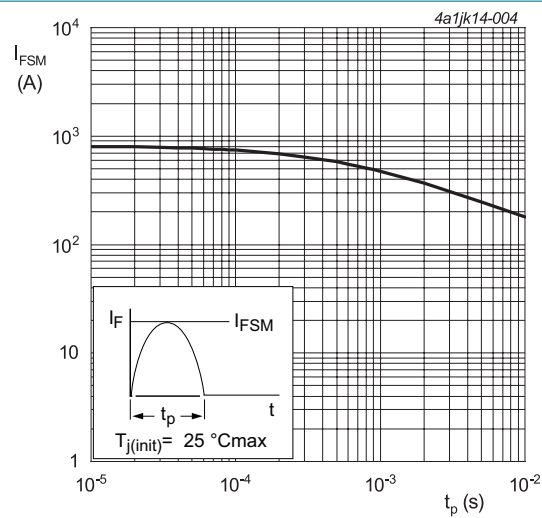
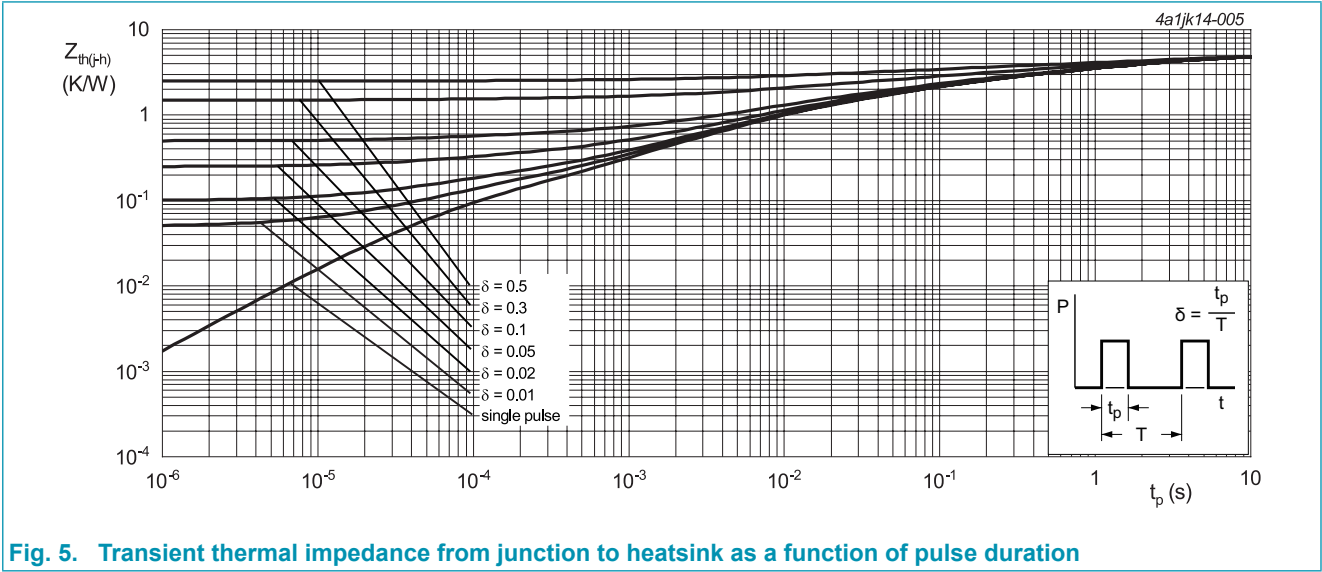


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound; Fig. 5		-	-	4.8	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W



10. Isolation characteristics

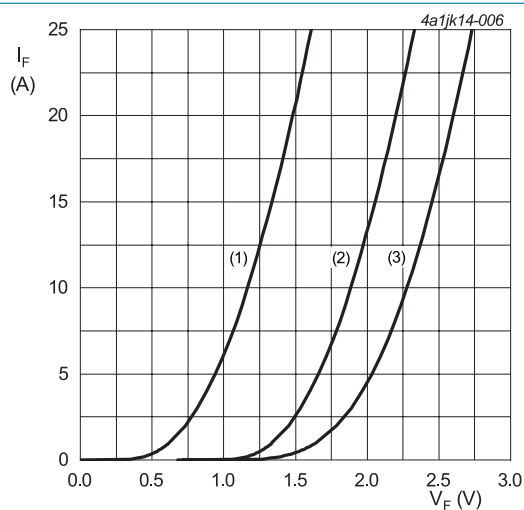
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free		-	-	2500	V
C_{isol}	isolation capacitance	f = 1 MHz; from cathode to external heatsink		-	10	-	pF

11. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; Fig. 6		-	1.90	2.60	V
		I _F = 20 A; T _j = 150 °C; Fig. 6		-	1.50	2.20	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C		-	0.5	30	μA
		V _R = 650 V; T _j = 150 °C		-	-	0.8	mA
Dynamic characteristics							
Q _r	reverse charge	I _F = 20 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7		-	85	-	nC
		I _F = 20 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7		-	350	-	nC
t _{rr}	reverse recovery time	I _F = 0.5 A; I _{rr} = 0.25 A; I _R = 1 A; T _j = 25 °C; Fig. 7		-	28	-	ns
		I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; Fig. 7		-	26	-	ns
		I _F = 20 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7		-	50	-	ns
		I _F = 20 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7		-	90	-	ns
I _{RM}	peak reverse recovery current	I _F = 20 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7		-	3.6	-	A
		I _F = 20 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7		-	7.5	-	A
E _{as}	non-repetitive avalanche energy	T _{j(init)} = 25 °C		16.8	-	-	mJ



$V_o = 1.714\text{ V}$; $R_s = 0.0241\text{ }\Omega$

(1) $T_j = 150\text{ °C}$; typical values

(2) $T_j = 150\text{ °C}$; maximum values

(3) $T_j = 25\text{ °C}$; maximum values

Fig. 6. Forward current as a function of forward voltage

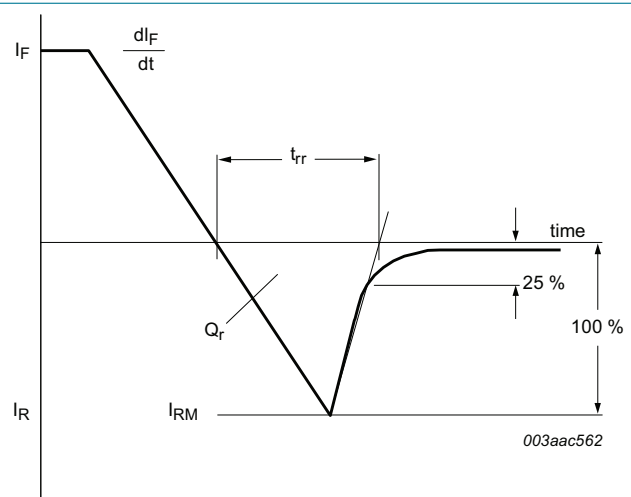
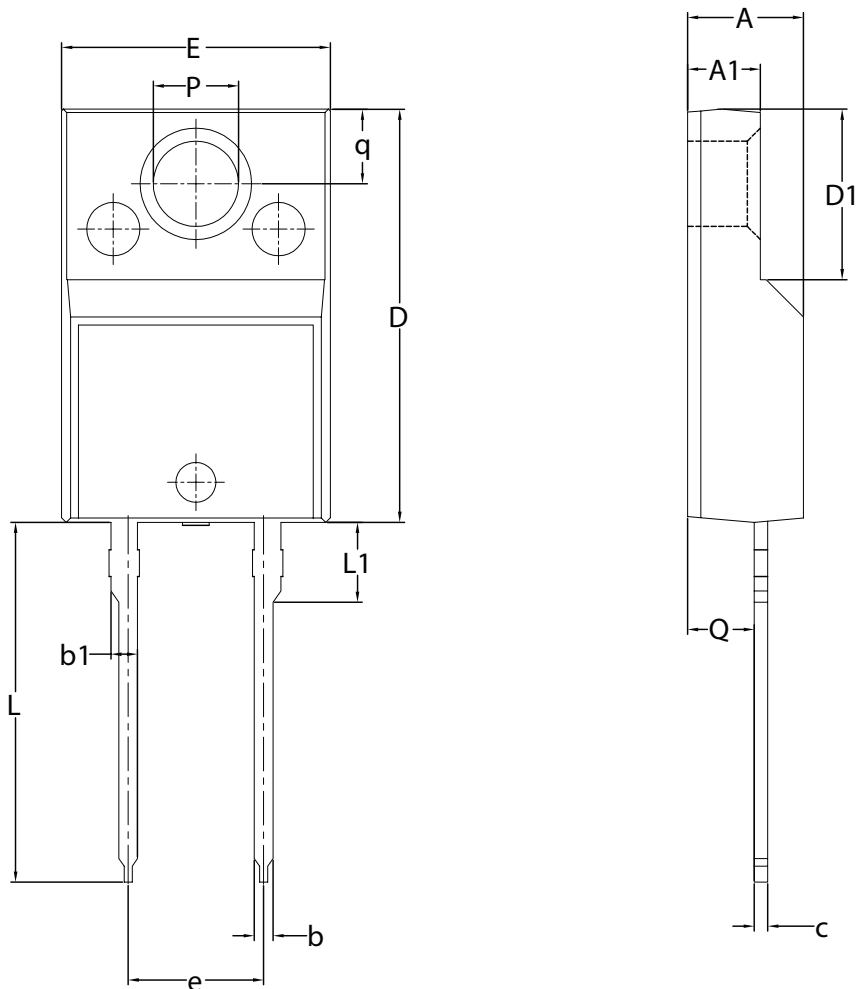


Fig. 7. Reverse recovery definitions; ramp recovery

12. Package outline

Plastic single-ended package; isolated heatsink mounted;1 mounting hole; 2 leads TO-220 'full pack' TO220F-2L



Unit	A	A1	b	b1	c	D	D1	E	e	L	L1	P	Q	q
min	4.00	2.50	0.70	0.90	0.40	15.20	6.30	9.80	5.08	13.50	2.80	3.00	2.30	2.60
max	4.60	3.10	0.90	1.10	0.70	15.80	6.50	10.30	(BSC)	14.40	3.30	3.40	2.80	3.00

Note:
1. All dimensions don't include mold flash and metal protrusion.

13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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